

Table of Contents

Foreword

Effect of Growth Parameters on Iron Incorporation in Semi-Insulating LEC Indium Phosphide

R. Fornari, M. Moriglioni, M. Thirumavalavan, A. Zappettini, M. Curti, G. Mignoni and M. Locci 1

Impurities Interactions in the Crystal Growth of LEC Gallium Arsenide

C. Mucchino, T. Görög, L. Zanotti, G. Mignoni and A. Catellani 7

Growth Striations in GaAs as Revealed by DSL Photoetching

E. Gilioli, J.L. Weyher, L. Zanotti and C. Mucchino 13

Impurity Segregation in the Growth of KF:Na⁺ Crystals

R. Bottazzi, C. Sanipoli and A. Scacco 19

Bulk Crystallization Kinetics of New TPI (Thermoplastic Poly Imide) by Differential Calorimetric Analysis

A. Maffezzoli 25

A New Vapour Phase Growth Approach to Organic Crystals

M. Zha, C. Paorici, C. Razzetti, M. Ardoino, L. Zanotti and G. Zuccalli 31

Vapour Growth of Organic Crystals by a Semi-Open Pizzarello (SOP) Technique

G. Zuccalli, M. Zha, L. Zanotti and C. Paorici 35

Solution Growth Method for High Anisotropy Organic Crystals

L. Zeng, M. Zha, M. Curti, L. Zanotti and C. Paorici 39

The Growth of Large Sucrose Crystals from Solution

G. Sgualdino, E. Scandale, D. Aquilano, G. Vaccari and G. Mantovani 43

Low-Temperature Preparation of Nanosized Crystalline LaFeO₃ Powders

E. Traversa, P. Nunziante, G. Gusmano, M. Sakamoto and Y. Sadaoka 47

Growth and Characterization of Single Crystals of High T_c Superconductors and Related Phases

F. Licci, T. Besagni and P. Ferro 53

Metal Nanocrystals in Amorphous Silica Matrix by the Sol-Gel Process

A. Licciulli, G. De, P. Mazzoldi, M. Catalano, L. Mirenghi and L. Tapfer 59

Deep Levels in Doped Indium Selenide Single Crystals

R. Rella, P. Siciliano and A. Tepore 65

The Formation and Stability of the Molten Zone in Single-Crystal Fiber Growth by the LHPG Method

V.V. Prokofiev, A. Kamshilin and T. Jaaskelainen 71

Growth of Si_{1-x}Ge_x Alloys by MBE

N. Pinto, R. Murri, L. Trojani, G. Majni, P. Mengucci and L. Lucchetti 79

Epitaxial Growth and Processing of InP Films in a 'Novel' Remote Plasma-MOCVD Apparatus

G. Bruno, M. Losurdo, P. Capezzuto, V. Capozzi, F.G. Lorusso and A. Minafra 85

InP Grown by Low-Pressure MOVPE Using Dimethylindium Pyrazole

G. Rossetto, G. Torzo, A. Camporese, P. Guerriero, M.L. Favaro, D. Ajò and P. Zanella 91

Growth and Characterization of High Efficiency GaAlAs/GaAs/Ge Solar Cells

G. Timò, C. Flores, R. Campesato, D. Passoni and B. Bollani 97

Growth and Characterization of InGaAsP/InGaAs MQW Structures Grown by MOCVD Technique

A. Antolini, G. Fornuto, C. Papuzza, D. Soldani and F. Taiariol 103

Growth and Realization of InGaAs/InP and InGaAs/InGaAsP Quantum Photonic Devices Grown by Chemical Beam Epitaxy

C. Rigo, C. Cacciatore, D. Campi, C. Coriasso, D. Soldani and A. Stano 109

MOCVD of CdTe on Foreign Substrates

S. Bernardi 115

Open Tube Iso-VPE of Hg_{1-x}Cd_xTe on CdTe/Sapphire Hybrid Substrates

F. Campanella and S. Bernardi 123

The Influence of an Ultrathin Pseudomorphic Interface Control Layer of Si on the Growth of SrF₂ on GaAs	129
S. Heun, M. Sugiyama, S. Maeyama, Y. Watanabe, K. Wada and M. Oshima	
Deposition of Doped and Undoped ZnO Thin Films fo Gas Sensors	137
M. Penza, C. Martucci, V.I. Anisimkin and L. Vasanelli	
Influence of the Deposition Parameters on the Physical Properties of Tin Oxide Thin Films	143
M. Di Giulio, A. Serra, A. Tepore, R. Rella, P. Siciliano and L. Mirenghi	
Growth of Thin Chalcopyrite CuInSe₂ Films by the Close Spaced Vapour Transport Process	149
M.L. Addonizio, S. Loretì, A. Agati, M. Pellegrino, L. Quercia, M.K. Jayaraj and A. Parretta	
Deposition and Characterization of Nitroso-Compound LB Films	155
R. Rella, P. Siciliano, A. Tepore, L. Valli and G. Vasapollo	
Dual Ion Beam Deposition and Characterizatio of TiO_x Thin Films	161
A. Rizzo, S. Cucurachi, L. Mirenghi, S. Scaglione, L. Vasanelli and E. Melissano	
Growth of Si:H Thin Films by Hot Filament CVD: μ-Crystalline to Amorphous Transition	167
R. Polini, V. Barbarossa, C. Minarini, A. Eray, A. Marucci and G. Mattei	
Triple Ion Beam Sputtering Deposition of β-FeSi₂	173
A. Valentini, E. Chimenti, A. Cola, G. Leo, F. Quaranta and L. Vasanelli	
Computer Modeling of the First Order Phase Transition Kinetics	181
V. Sessa, M. Fanfoni and M. Tomellini	
Modeling of Dislocation Formation during InP LEC Growth: A Comparison among the Thermoelastic and the Thermoplastic Approaches	187
S. Fogliani, M. Masi, S. Carrà, G. Guadalupi, B. Molinas and L. Meregalli	
Theoretical Equilibrium and Growth Morphologies of CaCO₃ Polymorphs: Aragonite and Cacite	193
D. Aquilano and M. Rubbo	
Some Considerations on the Microgravity Effects upon the Interfacial Free Energy	197
R. Tognato	
Detailed Modeling of Barrel Chemical Vapor Deposition Reactors	203
M. Masi, S. Fogliani and S. Carrà	
Modeling of the 2-D Particle Size Distribution Function in the Early Stage of Thin Film Growth	209
M. Tomellini	
Static Disorder in Si_{1-x}Ge_x Alloys and in Silicon on Insulator Structures	217
M. Servidori, S. Milita, F. Cembali and G. Lulli	
X-Ray Diffraction Study of Lattice Strain Relaxation in Mismatched III-V Heteroepitaxial Layers	223
P. Franzosi, L. Francesio and S. Gennari	
Investigation of Interface Abruptness in Strained InAs/In_{0.53}Ga_{0.47}As Quantum Wells	231
M.R. Bruni, N. Gambacorti, S. Kaciulis, G. Mattogno, M.G. Simeone and S. Viticoli	
Lattice Strain Analysis of VPE-Grown ZnS Epitaxial Layers on (001) GaAs by RBS - Channeling and High Resolution XRD Measurements	237
G. Leo, T. Peluso, N. Lovergne, A.M. Mancini, L. Vasanelli, C. Giannini, L. Tapfer, F. Romanato and A.V. Drigo	
Comparison between Optical and Structural Properties of ZnSe/GaAs(001) Heterostructures Grown by MBE under Different Beam Pressure Ratios	243
P. Prete, R. Cingolani, M. Lomascolo, T. Peluso, L. Vanzetti, L. Sorba and A. Franciosi	
Optical and Structural Characterization of Single Quantum Wells of InGaAs on GaAs MOCVD Grown Both on Exactly Oriented and Misoriented Substrates	249
A. Di Paola, D.M. Ritchie, M. Riva, F. Vidimari, C. Frigeri and A. Brinciotti	
Optical Investigation on Delta Doped PHEMT Structures	255
A. Brinciotti, A. Di Paola, D.M. Ritchie, M. Tromby and F. Vidimari	
Optical Properties of Zn_{1-x}Cd_xSe/ZnSe Quantum Well Lasers Fabricated by Molecular Beam Epitaxy	261
L. Calcagnile, G. Colì, R. Cingolani, L. Vanzetti, L. Sorba and A. Franciosi	
Optical and Electrical Properties of ZnOCdTe Thin Films	267
V. Augelli, T. Ligonzo, A. Pizzichetti, F. Quaranta, L. Schiavulli and A. Valentini	
SIMS-ETAAS Characterisation of Background Impurites in CdZnTe Bulk Samples	273
C. Gerardi, E. Milella, F. Campanella and S. Bernardi	

XPS and EPMA Study of CVD Diamond, Hydrogenated Amorphous Carbon and Graphite Films	
C. Manfredotti, M. Boero, C. Cassiago, P. Polesello, E. Vittone, L. Duò and E. Arnaboldi	279
Microstructure and Phase Morphology of Diamond Thin Films by Synchrotron Radiation X-Ray Diffraction	
G. Cappuccio, M. Leoni, P. Scardi, V. Sessa and M.L. Terranova	285
Morphological and Structural Investigations of Diamond Films Deposited on Substrates Covered by Carbon Layers	
M.L. Terranova, M. Rossi, V. Sessa and G. Vitali	291
Spectroscopic Characterization of a Substituted Phthalocyanine Thin Film Deposited by the Langmuir-Blodgett Technique	
L. Pasimeni, R. Rella, L. Troisi and L. Valli	297
Electrical Properties of C₆₀ Thin Films: Preliminary Results	
V. Augelli, G. Casamassima, T. Ligonzo, D. Loiacono, L. Schiavulli and A. Valentini	303